

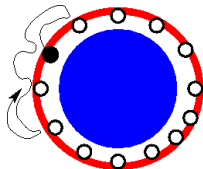
# The Non Equilibrium Steady State of Sparse Systems with Non Trivial Topology

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$$\mathcal{H}_{\text{total}} = \text{diag}\{E_n\} - f(t)\{V_{nm}\} + F\{W_{nm}\} + \mathcal{H}_{\text{Bath}}$$

- ▶ Doron Cohen (BGU) [1,2]
- ▶ Saar Rahav (Technion)[2]

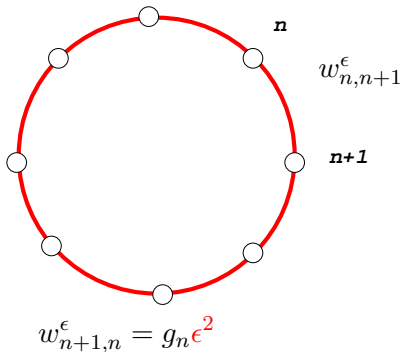
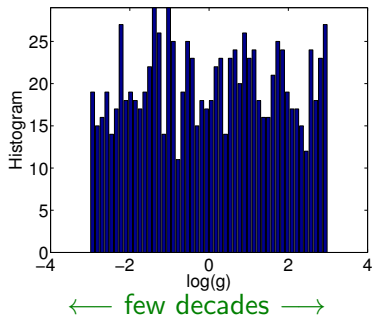


1. D. Hurowitz and D. Cohen, Europhysics Letters 93, 60002 (2011)
2. D. Hurowitz, S. Rahav and D. Cohen, Europhysics Letters 98, 20002 (2012).

# “Sparsity”

$$\mathcal{H}_{\text{total}} = \text{diag}\{E_n\} - f(t)\{V_{nm}\} + F(t)\{W_{nm}\}$$

Histogram of couplings



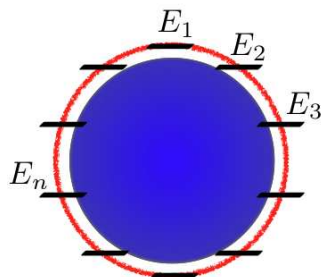
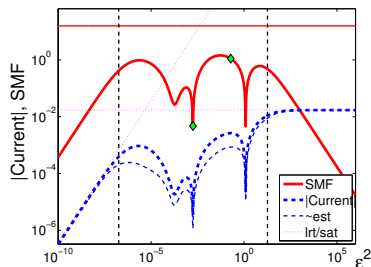
$$g_n = |V_{n,n+1}|^2 = \text{couplings}$$

“sparsity” = log wide distribution of couplings

# Current vs. driving

Driving  $\rightsquigarrow$  Stochastic Motive Force  $\rightsquigarrow$  Current

Regimes: LRT regime, Sinai regime, Saturation regime



$$I \sim \frac{1}{N} \bar{w} \exp \left[ -\frac{\mathcal{E}_n}{2} \right] 2 \sinh \left( \frac{\mathcal{E}_0}{2} \right)$$

Extent of the “Sinai regime” is determined by width of distribution of rates

# Master equation description of dynamics

$$\mathcal{H}_{\text{total}} = \text{diag}\{E_n\} - f(t)\{V_{nm}\} + F(t)\{W_{nm}\} + \mathcal{H}_{\text{Bath}}$$

Quantum master equation for the reduced probability matrix:

$$\frac{d\rho}{dt} = -i[\mathcal{H}_0, \rho] - \frac{\epsilon^2}{2}[V, [V, \rho]] + \mathcal{W}^\beta \rho \equiv \mathcal{W}\rho$$

Stochastic rate equation:

$$\frac{dp_n}{dt} = \sum_m w_{nm} p_m - w_{mn} p_n$$

The transition rates:

$$w_{nm} = w_{nm}^\epsilon + w_{nm}^\beta$$

$$w_{nm}^\epsilon = w_{mn}^\epsilon = g_{nm} \epsilon^2$$

Steady state equation:

$$\dot{\rho} = \mathcal{W}\rho = 0$$

$$\frac{w_{nm}^\beta}{w_{mn}^\beta} = \exp\left[-\frac{E_n - E_m}{T_B}\right]$$

# The Stochastic Motive Force (SMF)

If we had only a bath

$$\frac{w_{nm}}{w_{mn}} = \exp \left[ -\frac{E_n - E_m}{T_B} \right]$$

We define a “field”

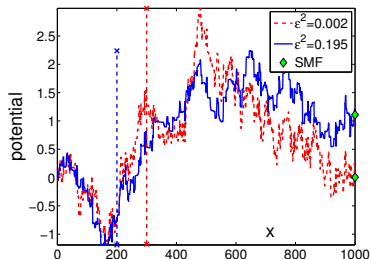
$$\mathcal{E}(x) \equiv \ln \left[ \frac{w_{nm}}{w_{mn}} \right]$$

and “potentials”

$$\mathcal{E}(x_1 \rightsquigarrow x_2) = \int_{x_1}^{x_2} \mathcal{E}(x) dx \quad \text{[potential variation]}$$

$$\mathcal{E}_{\cap} \equiv \text{maximum} \left\{ |\mathcal{E}(x_1 \rightsquigarrow x_2)| \right\} \quad \text{[activation barrier]}$$

$$\mathcal{E}_{\circ} \equiv \oint \mathcal{E}(x) dx \quad \text{if no driving} = 0 \quad \text{[SMF]}$$

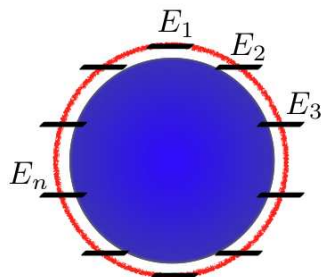
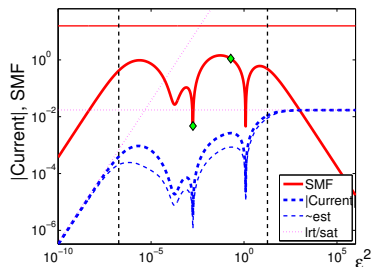


With driving,  $\mathcal{E}_{\circ} \neq 0$ . This means  $\prod_n w_{n,n+1} \neq \prod_n w_{n+1,n}$ .

# Current vs. driving

Driving  $\rightsquigarrow$  Stochastic Motive Force  $\rightsquigarrow$  Current

Regimes: LRT regime, Sinai regime, Saturation regime



$$I \sim \frac{1}{N} \bar{w} \exp\left[-\frac{\mathcal{E}_n}{2}\right] 2 \sinh\left(\frac{\mathcal{E}_0}{2}\right)$$

Extent of the “Sinai regime” is determined by width of distribution of rates

## Emergence of the “Sinai regime”

Sinai [1982]: Transport in a chain with random transition rates.

Assume transition rates are uncorrelated.

↪ build up of a potential barrier  $\mathcal{E}_n \propto \sqrt{N}$ .

↪ exponentially small current.

But... we have telescopic correlations:  $\mathcal{E}_{n,n+1} \sim \Delta_n \equiv (E_n - E_{n+1})$

Yet... we have sparsely distributed couplings:  $w_{n,n+1}^\epsilon = g_n \epsilon^2$

$$\mathcal{E}_0 \approx - \sum_n \left[ \frac{1}{1 + g_n \epsilon^2} \right] \frac{\Delta_n}{T_B} \sim \frac{1}{T_B} \begin{cases} \epsilon^2, & \epsilon^2 < 1/g_{\max} \\ 1/\epsilon^2, & \epsilon^2 > 1/g_{\min} \\ [\pm] \sqrt{N} \Delta, & \text{otherwise} \end{cases}$$

Build up may occur if  $g_n$  are from a **log-wide** distribution.

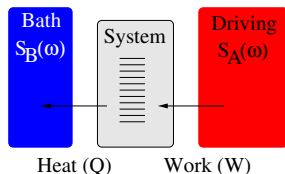
$$I \sim \frac{1}{N} \bar{w} \exp \left[ -\frac{\mathcal{E}_0}{2} \right] 2 \sinh \left( \frac{\mathcal{E}_0}{2} \right)$$

# Generalized Fluctuation-Dissipation phenomenology

$$\mathcal{H}_{\text{total}} = E_n \delta_{nm} - f(t) V_{nm} + F(t) W_{nm}$$

$$\dot{W} = \text{rate of heating} = \frac{D(\epsilon)}{T_{\text{system}}}$$

$$\dot{Q} = \text{rate of cooling} = \frac{D_B}{T_B} - \frac{D_B}{T_{\text{system}}}$$



Hence at the NESS:

$$T_{\text{system}} = \left(1 + \frac{D(\epsilon)}{D_B}\right) T_B$$

$$\dot{Q} = \dot{W} = \frac{1/T_B}{D_B^{-1} + D(\epsilon)^{-1}}$$

Experimental way to extract response:

$$\dot{Q}(\infty) = \frac{D_B}{T_B}$$

$$D(\epsilon) = \frac{\dot{Q}(\epsilon)}{\dot{Q}(\infty) - \dot{Q}(\epsilon)} D_B$$

$D(\epsilon)$  exhibits LRT to SLRT crossover  
SLRT requires resistor network calculation

$$D(\epsilon) = \left[ \left( \frac{w_n}{w_\beta + w_n} \right) \right] \left[ \left( \frac{1}{w_\beta + w_n} \right) \right]^{-1}$$

$$w_n = g_n \epsilon^2$$

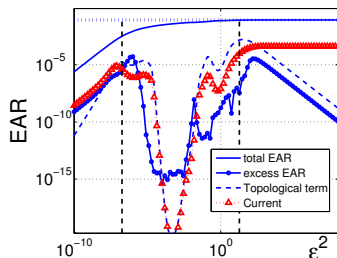
$$D_{[\text{LRT}]} = \overline{g_n} \epsilon^2 \quad [\text{weak driving}]$$

$$D_{[\text{SLRT}]} = [\overline{1/g_n}]^{-1} \epsilon^2 \quad [\text{strong driving}]$$



# Topological term in EAR formula

$$\begin{aligned}\dot{Q} &= \sum_n \left[ w_{\leftarrow n}^\beta p_n - w_{\rightarrow n}^\beta p_{n-1} \right] \Delta_n \\ &\approx \left[ \frac{D_B}{T_B} - \frac{D_B}{T^{(0)}} \right] + T_B \mathcal{E}_\odot I \\ &\approx \frac{D_B}{T_B} \left[ \overline{(g_n \epsilon^2)} - (g_n \epsilon^2)^2 + \text{Var}(g) \epsilon^4 \right]\end{aligned}$$



The EAR is correlated with the current.

## Digression - derivation of the cooling rate formula

$$\dot{Q} = \text{cooling rate} = -\sum_{n,m} (E_n - E_m) w_{nm}^{\beta} p_m$$

$$p_n - p_m = \text{occupation imbalance} = \left[ 2 \tanh \left( -\frac{E_n - E_m}{2T_{nm}} \right) \right] \bar{p}_{nm}$$

$$w_{nm}^{\beta} - w_{mn}^{\beta} = \text{up/down transitions imbalance} = \left[ 2 \tanh \left( -\frac{E_n - E_m}{2T_B} \right) \right] \bar{w}_{nm}^{\beta}$$

$$\dot{Q} = \frac{1}{2} \sum_{n,m} (E_n - E_m)^2 \frac{\bar{w}_{nm}^{\beta}}{T_B} \bar{p}_{nm} - \frac{1}{2} \sum_{n,m} (E_n - E_m)^2 \frac{\bar{w}_{nm}^{\beta}}{T_{nm}} \bar{p}_{nm} = \frac{D_B}{T_B} - \frac{D_B}{T_{\text{system}}}$$

definition of the diffusion coefficient:  $D_B \equiv \overline{\left[ \frac{1}{2} \sum_n (E_n - E_m)^2 w_{nm}^{\beta} \right]}$

definition of effective system temperature:  $\frac{1}{T_{\text{system}}} \equiv \overline{\left[ \frac{1}{T_{nm}} \right]}$

# The quantum mechanical steady state

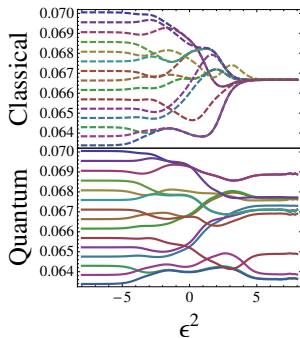
## Stochastic

$$\frac{dp_n}{dt} = \sum_m w_{nm} p_m - w_{mn} p_n$$

$$I_{n \rightarrow m} = w_{mn} p_n - w_{nm} p_m \equiv \text{tr}(\hat{I}_{n \rightarrow m} \rho)$$

$$\hat{I}_{n \rightarrow m}^\epsilon = |n\rangle w_{mn}^\epsilon \langle n| - |m\rangle w_{nm}^\epsilon \langle m|$$

$$\hat{I}_{n \rightarrow m}^\beta = |n\rangle w_{mn}^\beta \langle n| - |m\rangle w_{nm}^\beta \langle m|$$

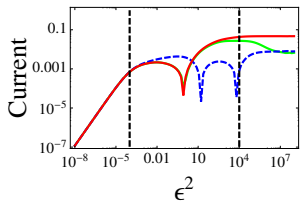


## Quantum

$$\frac{d\rho}{dt} = -i[\mathcal{H}_0, \rho] - \frac{\epsilon^2}{2}[V, [V, \rho]] + \mathcal{W}^\beta \rho$$

$$\hat{I}_{n \rightarrow m}^\epsilon = i\epsilon^2 [\hat{J}^{nm}, \hat{V}]$$

$$\hat{J}^{nm} = i(|m\rangle V_{mn} \langle n| - |n\rangle V_{nm} \langle m|)$$



## Summary of main results

1. Due to the **sparsity** of the perturbation matrix, the NESS is of glassy nature [1].
2. An extension of the Fluctuation-Dissipation phenomenology has been proposed [1].
3. A log-wide distribution of couplings is required in order to have a **Sinai regime**.
4. The **topological term** in the EAR is correlated with the current but sub-linear in driving intensity.
5. Novel saturation effect in the quantum model.
6. The quantum **current operator** in the reduced description includes off diagonal elements of the probability matrix.

[1] D. Hurowitz and D. Cohen, Europhysics Letters 93, 60002 (2011).

# References and Acknowledgements

1. D. Hurowitz and D. Cohen, Europhysics Letters 93, 60002 (2011).
  2. D. Hurowitz, S. Rahav and D. Cohen, Europhysics Letters 98, 20002 (2012).
- ▶ **Sparsity**: Austin, Wilkinson, Prosen, Robnik, Alhassid, Levine, Fyodorov, Chubykalo, Izrailev, Casati
  - ▶ **Energy absorption by sparse systems**: Cohen, Kottos, Schanz, Wilkinson, Mehlig
  - ▶ **Network theory**: Schnakenberg, Zia, Hill
  - ▶ **Sinai physics**: Sinai, Derrida, Pomeau, Burlatsky, Oshanin, Mogutov, Moreau, Bouchard

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